MPSA64 is a Preferred Device

# **Darlington Transistors**

# **PNP Silicon**

## **Features**

• Pb-Free Packages are Available\*

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage  MPSA62  MPSA63/64	V <sub>CES</sub>	-20 -30	Vdc
Collector – Base Voltage  MPSA62  MPSA63/64	V <sub>CBO</sub>	-20 -30	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	-10	Vdc
Collector Current – Continuous	Ic	-500	mAdc
Total Device Dissipation  @ T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

## THERMAL CHARACTERISTICS

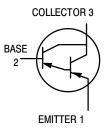
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	83.3	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



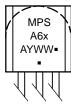
## ON Semiconductor®

http://onsemi.com



#### **MARKING DIAGRAM**





x = 2, 3, or 4

A = Assembly Location

Y = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS		·			
Collector – Emitter Breakdown Voltage ( $I_C = -100 \mu Adc, V_{BE} = 0$ )	MPSA62 MPSA63, MPSA64	V <sub>(BR)CES</sub>	-20 -30	_ _	Vdc
Collector Cutoff Current $(V_{CB} = -15 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -30 \text{ Vdc}, I_E = 0)$	MPSA62 MPSA63, MPSA64	Ісво	_ _	-100 -100	nAdc
Emitter Cutoff Current (V <sub>EB</sub> = -10 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	-	-100	nAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain ( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -5.0 \text{ Vdc}$ )	MPSA63 MPSA64 MPSA62	h <sub>FE</sub>	5,000 10,000 20,000	- - -	-
$(I_C = -100 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	MPSA63 MPSA64		10,000 20,000	_	
Collector – Emitter Saturation Voltage ( $I_C = -10 \text{ mAdc}$ , $I_B = -0.01 \text{ mAdc}$ ) ( $I_C = -100 \text{ mAdc}$ , $I_B = -0.1 \text{ mAdc}$ )	MPSA62 MPSA63, MPSA64	V <sub>CE(sat)</sub>		-1.0 -1.5	Vdc
Base – Emitter On Voltage ( $I_C = -10$ mAdc, $V_{CE} = -5.0$ Vdc) ( $I_C = -100$ mAdc, $V_{CE} = -5.0$ Vdc)	MPSA62 MPSA63, MPSA64	V <sub>BE(on)</sub>	_ _	-1.4 -2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain — Bandwidth Product (Note 2) (I <sub>C</sub> = -100 mAdc, V <sub>CE</sub> = -5.0 Vdc, f = 100 MHz)	MPSA63, MPSA64	f <sub>T</sub>	125	_	MHz

<sup>1.</sup> Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

# **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
MPSA62	TO-92	5000 Units / Bulk	
MPSA63	TO-92	5000 Units / Bulk	
MPSA63G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPSA63RLRA	TO-92	2000 / Tape & Reel	
MPSA63RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPSA63RLRM	TO-92	2000 / Ammo Pack	
MPSA63RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack	
MPSA63RLRP	TO-92	2000 / Ammo Pack	
MPSA63RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack	
MPSA63ZL1	TO-92	2000 / Ammo Pack	
MPSA63ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack	
MPSA64	TO-92	5000 Units / Bulk	
MPSA64G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPSA64RLRA	TO-92	2000 / Tape & Reel	
MPSA64RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel	
MPSA64RLRM	TO-92	2000 / Ammo Pack	
MPSA64RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>2.</sup>  $f_T = |h_{fe}| \cdot f_{test}$ .

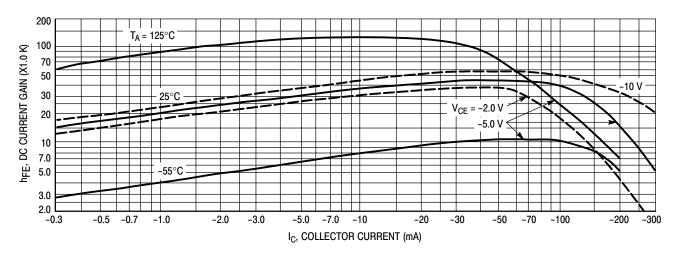


Figure 1. DC Current Gain

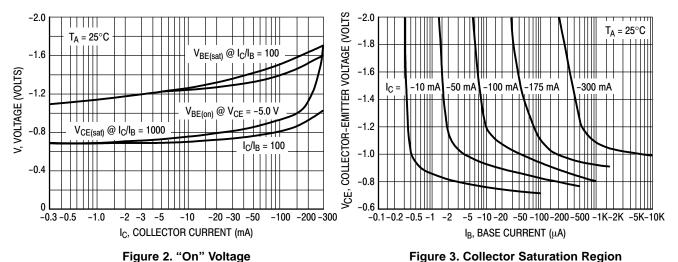
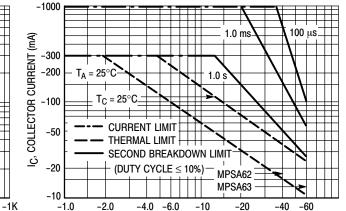


Figure 2. "On" Voltage



IhFEI, HIGH FREQUENCY CURRENT GAIN 4.0 \_ T<sub>A</sub> = 25°C 3.0 2.0 1.0 0.4 0.2

 $V_{CE} = -5.0 \text{ V}$ 

f = 100 MHz

-2.0

-1.0

IC, COLLECTOR CURRENT (mA) Figure 4. High Frequency Current Gain

-50

-100 -200

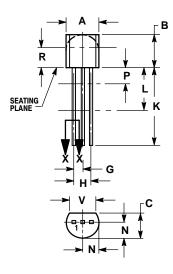
-500

-2.0 -4.0 -6.0 -10 -40 -1.0 V<sub>CE</sub>, COLLECTOR VOLTAGE (VOLTS)

Figure 5. Active Region, Safe Operating Area

## PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL** 





- DIMENSIONING AND TOLERANCING PER ANSI
  - Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND
- BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.115		2.93		
V	0 135		3 43		

STYLE 1: PIN 1. EMITTER COLLECTOR

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